## NSN 5961-01-212-8007

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-212-8007 **Inclosure Material:** Plastic **Overall Length:** 0.285 inches **Overall Height:** 0.145 inches **Overall Width:** 0.185 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-237 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 250.00 nanoamperes zero-gate-voltage source current preset **Transfer Ratio:** 25.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: